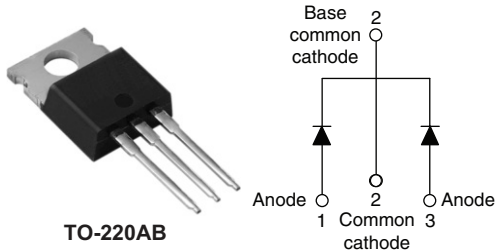


Schottky Rectifier, 2 x 15 A



FEATURES

- 150 °C T_J operation
- Center tap TO-220 package
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level



RoHS*
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	2 x 15 A
V_R	35/45 V
I_{RM}	40 mA at 125 °C

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform (per device)	30	A
V_{RRM}		35/45	V
I_{FRM}	$T_C = 130$ °C (per leg)	30	A
I_{FSM}	$t_p = 5$ μ s sine	1060	
V_F	30 Apk, $T_J = 125$ °C	0.73	V
T_J	Range	- 65 to 150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	MBR2535CTPbF	MBR2545CTPbF	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current per leg per device	$I_{F(AV)}$	$T_C = 130$ °C, rated V_R	15	A
			30	
Peak repetitive forward current per leg	I_{FRM}	Rated V_R , square wave, 20 kHz, $T_C = 130$ °C	30	
Non-repetitive peak surge current	I_{FSM}	5 μ s sine or 3 μ s rect. pulse	1060	
		Surge applied at rated load conditions halfwave, single phase, 60 Hz	150	
Non-repetitive avalanche energy per leg	E_{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 8$ mH	16	mJ
Repetitive avalanche current per leg	I_{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	2	A

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	30 A	$T_J = 25\text{ }^\circ\text{C}$	0.82	V
			$T_J = 125\text{ }^\circ\text{C}$	0.73	
Maximum instantaneous reverse current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.2	mA
		$T_J = 125\text{ }^\circ\text{C}$		40	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J$ maximum		0.355	V
Forward slope resistance	r_t			12.3	$m\Omega$
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		700	pF
Typical series inductance	L_S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s

Note

(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction temperature range	T_J			- 65 to 150	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}			- 65 to 175	
Maximum thermal resistance, junction to case per leg	R_{thJC}	DC operation		1.5	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style TO-220AB		MBR2535CT	
				MBR2545CT	



MBR25..CTPbF Series

Schottky Rectifier, 2 x 15 A Vishay High Power Products

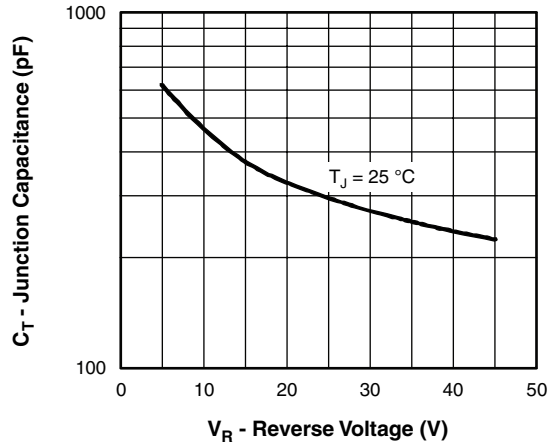
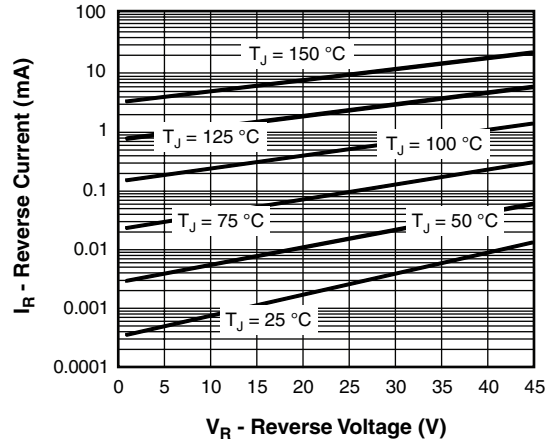
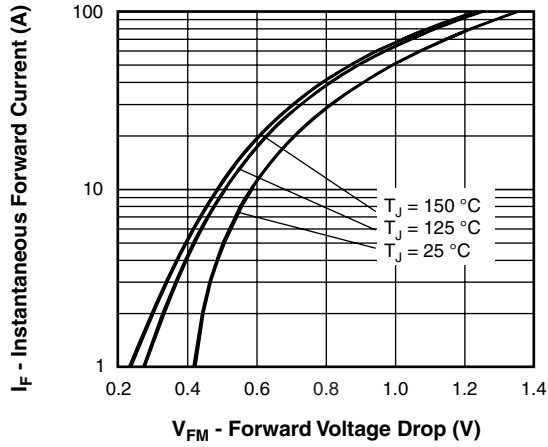


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

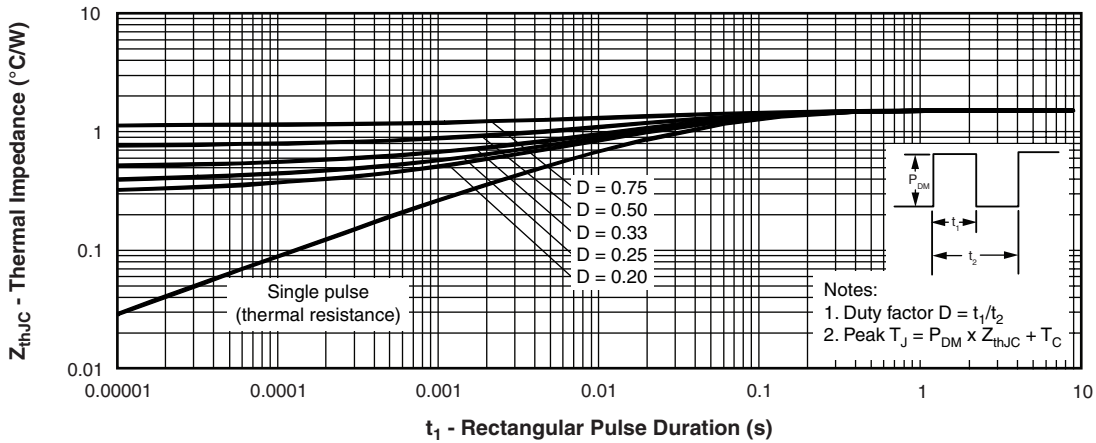


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

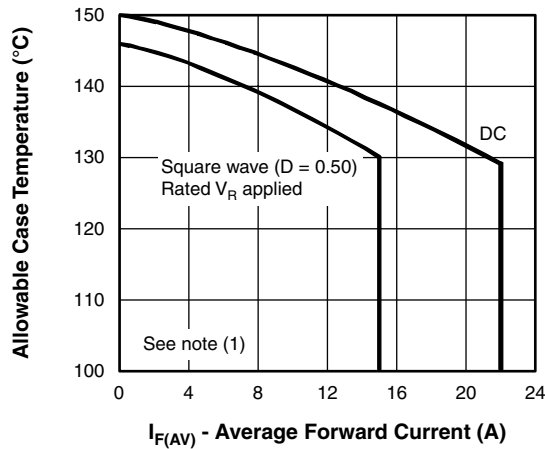


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

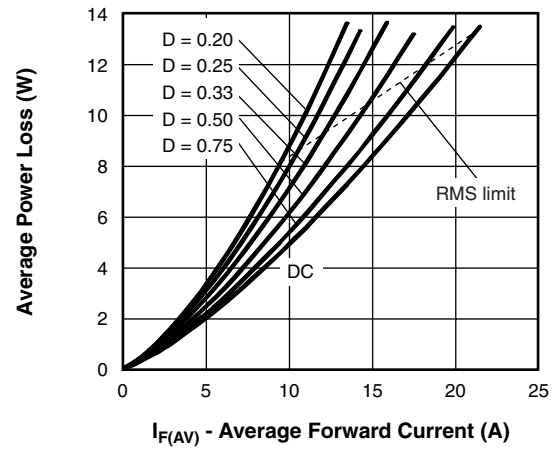


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

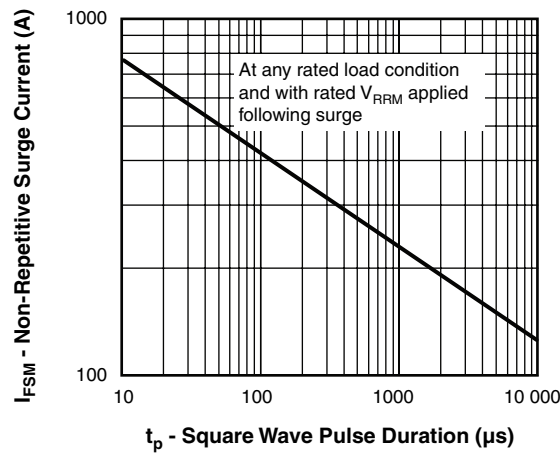


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

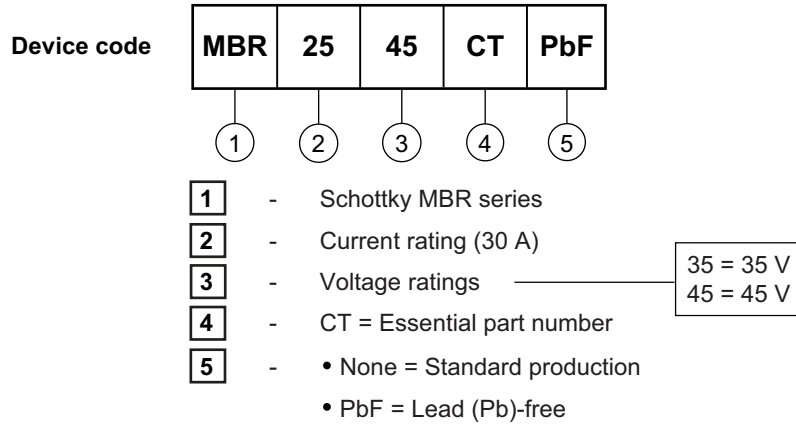
- (1) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 $P_{d_{REV}}$ = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



MBR25..CTPbF Series

Schottky Rectifier, 2 x 15 A Vishay High Power Products

ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95222
Part marking information	http://www.vishay.com/doc?95225



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